NSN 5961-00-519-2733

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
4.692 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-93
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Overall Width Across Flats:
1.231 inches
Thread Size:
0.750 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1200.0 nonrepetitive peak reverse voltage and 1000.0 forward voltage, peak and 1000.0 reverse voltage, peak
Current Rating Per Characteristic:
4500.00 amperes peak forward surge current nanoamperes
Power Rating Per Characteristic:
16.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius case
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 3 uninsulated wire lead w/terminal lug
Specification Data:
80131-release 5099 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A11000